TOSHIBA PHOTOCOUPLER GaAℓAs IRED & PHOTO-IC

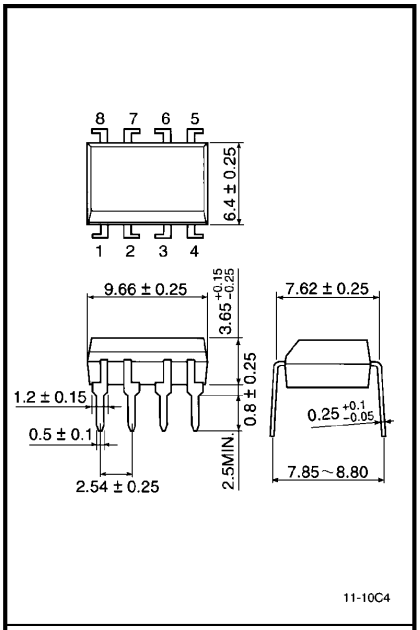
TLP251

INVERTER FOR AIR CONDITIONOR
INDUCTION HEATING
TRANSISTOR INVERTER
POWER MOS FET GATE DRIVE
IGBT GATE DRIVE

The TOSHIBA TLP251 consists of a GaAℓAs light emitting diode and a integrated photodetector.
This unit is 8-lead DIP package.
TLP251 is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP251 is capable of "direct" gate drive of lower power IGBTs. (~15A)

- Input Threshold Current : I_F = 5mA (Max.)
- Supply Current (I_{CC}) : 11mA (Max.)
- Supply Voltage (V_{CC}) : 10–35V
- Output Current (I_O) : ±0.4A (Max.)
- Switching Time (t_{pLH}/t_{pHL}) : 1μs (Max.)
- Isolation Voltage : 2500Vrms (Min.)
- UL Recognized : UL1577, File No. E67349

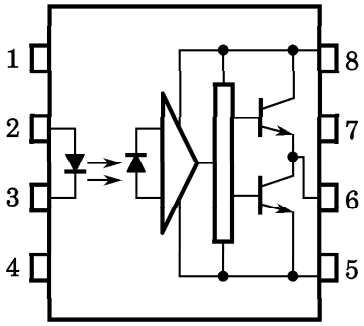
Unit in mm



TOSHIBA 11-10C4

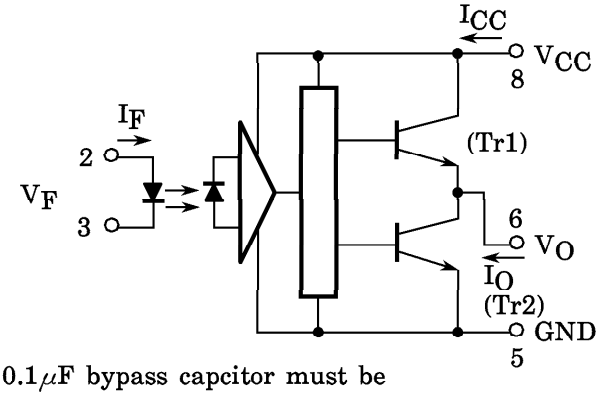
Weight : 0.54g

PIN CONFIGURATION (TOP VIEW)



1 : N.C.
2 : ANODE
3 : CATHODE
4 : N.C.
5 : GND
6 : V_O (OUTPUT)
7 : N.C.
8 : V_{CC}

SCHMATIC



A 0.1μF bypass capcitor must be connected between pin 8 and 5 (See Note 5).

TRUTH TABLE

		Tr1	Tr2
Input LED	ON	ON	OFF
	OFF	OFF	ON

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current		I_F	20	mA
	Forward Current Derating (Ta ≧ 70°C)		$\Delta I_F / \Delta Ta$	−0.36	mA / °C
	Peak Transient Forward Current (Note 1)		I_{FPT}	1	A
	Reverse Voltage		V_R	5	V
	Junction Temperature		T_j	125	°C
DETECTOR	"H" Peak Output Current ($P_W \leqq 2.0\mu s$, f ≦ 15kHz) (Note 2)		I_{OPH}	−0.4	A
	"L" Peak Output Current ($P_W \leqq 2.0\mu s$, f ≦ 15kHz) (Note 2)		I_{OPL}	0.4	A
	Output Voltage	(Ta ≦ 70°C)	V_O	35	V
		(Ta = 85°C)		24	
	Supply Voltage	(Ta ≦ 70°C)	V_{CC}	35	V
		(Ta = 85°C)		24	
	Output Voltage Derating (Ta ≧ 70°C)		$\Delta V_O / \Delta Ta$	−0.73	V / °C
	Supply Voltage Derating (Ta ≧ 70°C)		$\Delta V_{CC} / \Delta Ta$	−0.73	V / °C
	Junction Temperature		T_j	125	°C
Operating Frequency (Note 3)			f	25	kHz
Operating Temperature Range			T_{opr}	−20~85	°C
Storage Temperature Range			T_{stg}	−55~125	°C
Lead Soldering Temperature (10s)			T_{sol}	260	°C
Isolation Voltage (AC, 1min., R.H. ≦ 60%) (Note 4)			BV_S	2500	Vrms

(Note 1) Pulse width $P_W \leqq 1\mu s$, 300pps

(Note 2) Expornential Waveform

(Note 3) Expornential Waveform, $I_{OPH} \leqq -0.25A$ ($\leqq 2.0\mu s$), $I_{OPL} \leqq +0.25A$ ($\leqq 2.0\mu s$)

(Note 4) Device considerd a two terminal device : pins 1,2,3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

(Note 5) A ceramic capacitor (0.1μF) should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1cm.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.		UNIT
Input Current, ON	$I_{F\,(ON)}$	7	8	10		mA
Input Voltage, OFF	$V_{F\,(OFF)}$	0	—	0.8		V
Supply Voltage	V_{CC}	10	—	30	20	V
Peak Output Current	I_{OPH} / I_{OPL}	—	—	±0.1		A
Operating Temperature	T_{opr}	−20	25	70	85	°C

ELECTRICAL CHARACTERISTICS (Ta = − 20~70°C, Unless otherwise specified)

CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION		MIN.	TYP.*	MAX.	UNIT
Input Forward Voltage		V_F	—	I_F=10mA, Ta=25°C		—	1.6	1.8	V
Temperature Coefficient of Forward Voltage		$\Delta V_F / \Delta Ta$	—	I_F=10mA		—	−2.0	—	mV / °C
Input Reverse Current		I_R	—	V_R=5V, Ta=25°C		—	—	10	μA
Input Capacitance		C_T	—	V=0, f=1MHz, Ta=25°C		—	45	250	pF
Output Current	"H" Level	I_{OPH}	3	V_{CC}=30V (*1)	I_F=10mA V_{8-6}=4V	−0.1	−0.25	—	A
	"L" Level	I_{OPL}	2		I_F=0 V_{6-5}=2.5V	0.1	0.2	—	
Output Voltage	"H" Level	V_{OH}	4	V_{CC1}=+15V, V_{EE1}=−15V R_L=200Ω, I_F=5mA		11	13.2	—	V
	"L" Level	V_{OL}	5	V_{CC1}=+15V, V_{EE1}=−15V R_L=200Ω, V_F=0.8V		—	−14.5	−12.5	
Supply Current	"H" Level	I_{CCH}	—	V_{CC}=30V, I_F=10mA Ta=25°C		—	7.5	—	mA
				V_{CC}=30V, I_F=10mA		—	—	11	
	"L" Level	I_{CCL}	—	V_{CC}=30V, I_F=0mA Ta=25°C		—	8	—	
				V_{CC}=30V, I_F=0mA		—	—	11	
Threshold Input Current	"Output L→H"	I_{FLH}	—	V_{CC1}=+15V, V_{EE1}=−15V R_L=200Ω, V_O>0V		—	1.2	5	mA
Threshold Input Voltage	"Output H→L"	V_{FHL}	—	V_{CC1}=+15V, V_{EE1}=−15V R_L=200Ω, V_O<0V		0.8	—	—	V
Supply Voltage		V_{CC}	—			10	—	35	V
Capacitance (Input-Output)		C_S	—	Vs=0, f=1MHz Ta=25°C		—	1.0	2.0	pF
Resistance (Input-Output)		R_S	—	Vs=500V, Ta=25°C R.H.≦60%		1×10^{12}	10^{14}	—	Ω

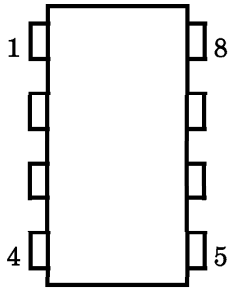
* All typical values are at Ta=25°C (*1) : Duration of I_O time≦50μs

SWITCHING CHARACTERISTICS (Ta = −20~70°C, Unless otherwise specified)

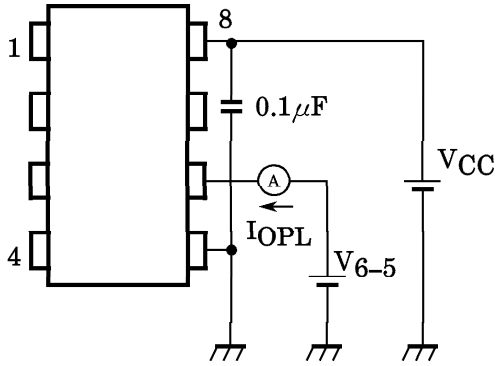
CHARACTERISTIC		SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.*	MAX.	UNIT
Propagation Delay Time	L→H	t_{pLH}	6	I_F = 8mA V_{CC1} = +15V, V_{EE1} = −15V R_L = 200Ω	—	0.25	1.0	μs
	H→L	t_{pHL}			—	0.25	1.0	
Output Rise Time		t_r			—	—	—	
Output Fall Time		t_f			—	—	—	
Common Mode Transient Immunity at High Level Output		C_{MH}	7	V_{CM} = 600V, I_F = 8mA V_{CC} = 30V, Ta = 25°C	−5000	—	—	V / μs
Common Mode Transient Immunity at Low Level Output		C_{ML}	7	V_{CM} = 600V, I_F = 0mA V_{CC} = 30V, Ta = 25°C	5000	—	—	V / μs

* All typical values are at Ta = 25°C

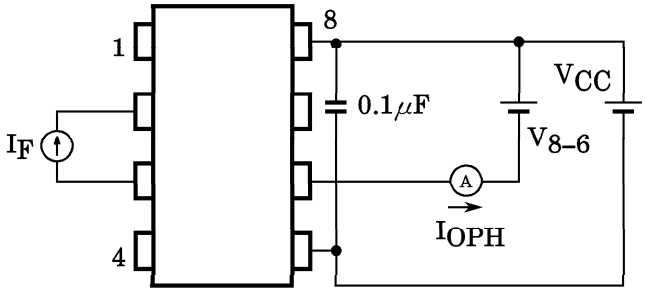
TEST CIRCUIT 1 :



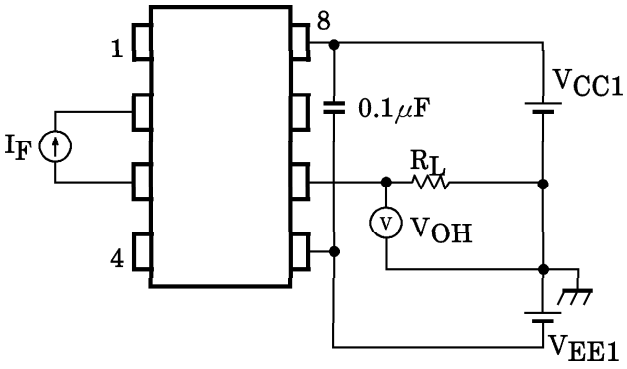
TEST CIRCUIT 2 : I_{OPL}



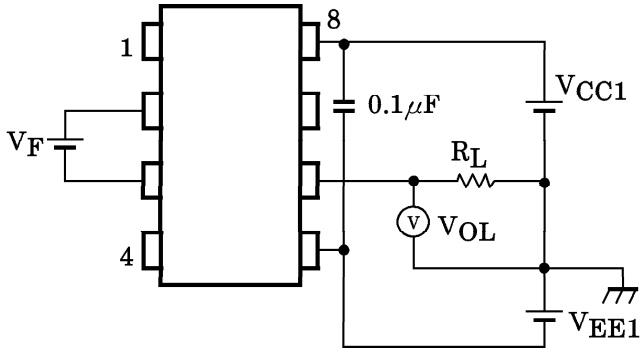
TEST CIRCUIT 3 : I_{OPH}



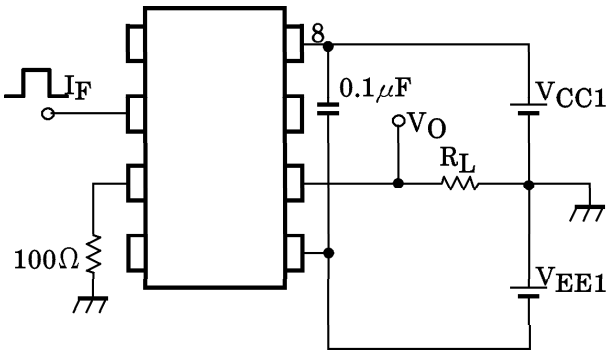
TEST CIRCUIT 4 : V_{OH}

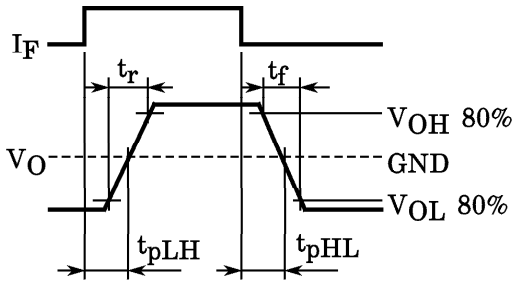


TEST CIRCUIT 5 : V_{OL}

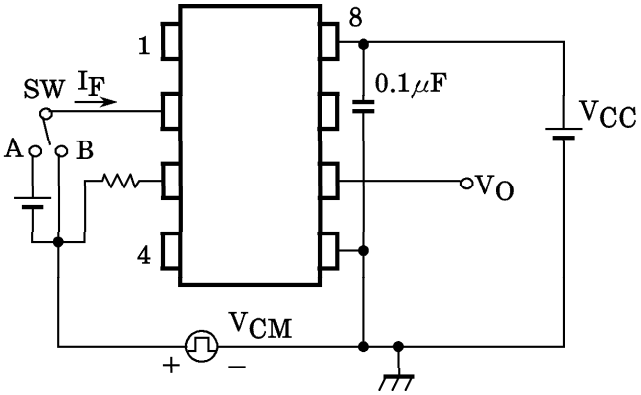


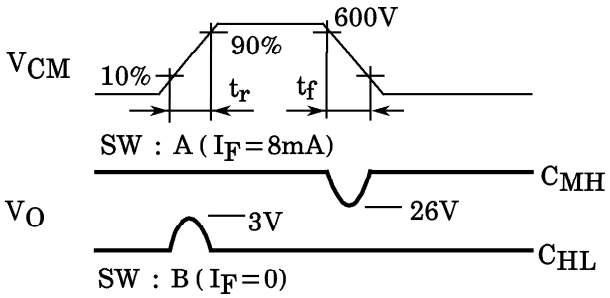
TEST CIRCUIT 6 : t_{pLH}, t_{pHL}, t_r, t_f





TEST CIRCUIT 7 : C_{MH}, C_{ML}



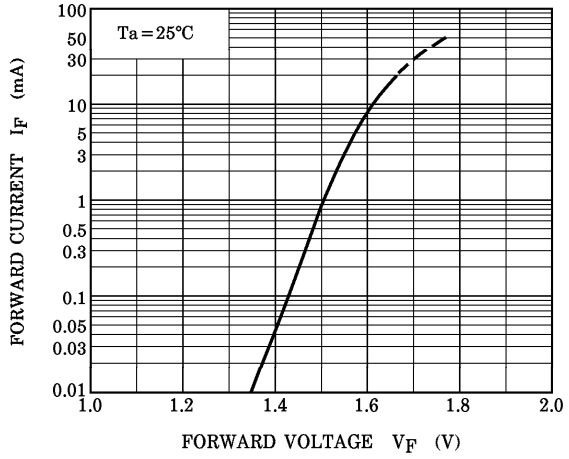


$$C_{ML} = \frac{480\,(V)}{t_r\,(\mu s)}$$

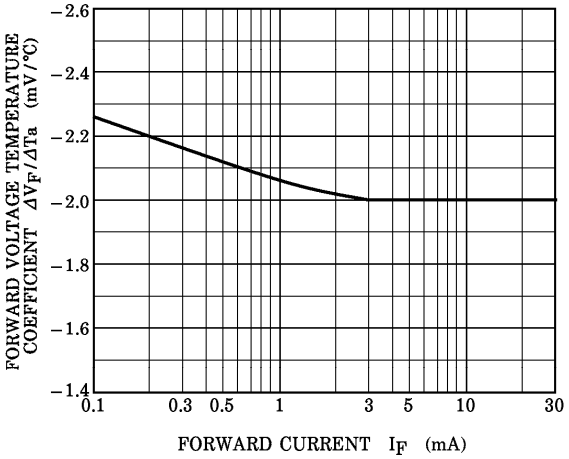
$$C_{MH} = \frac{480(V)}{t_f\,(\mu s)}$$

C_{ML} (C_{MH}) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.

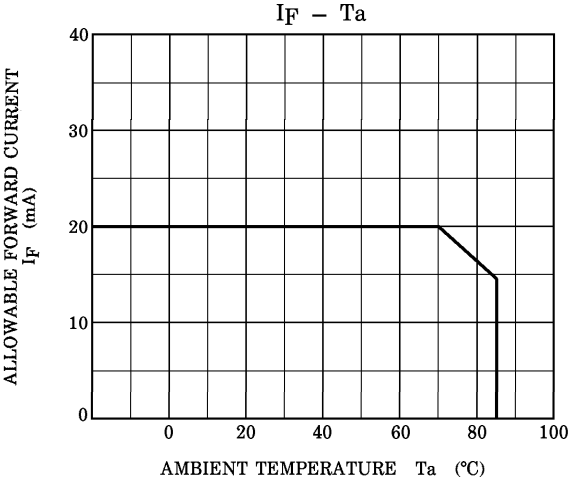
$I_F - V_F$



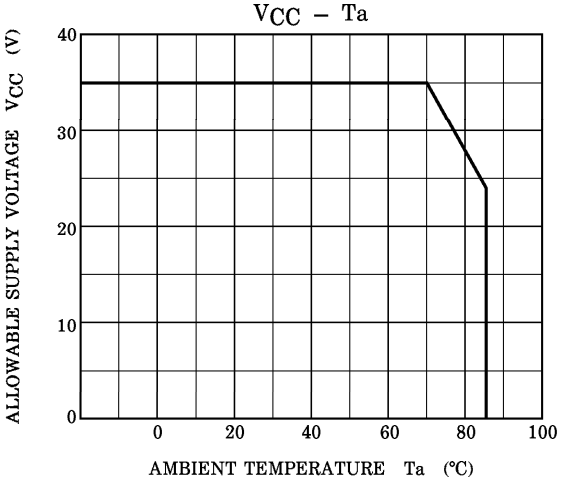
$\Delta V_F / \Delta V_F - I_F$



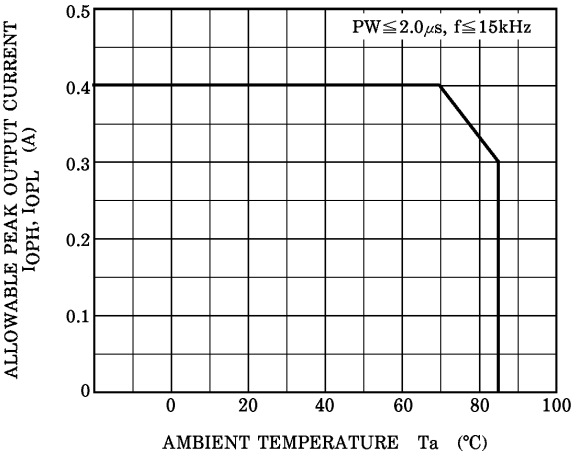
$I_F - Ta$



$V_{CC} - Ta$



$I_{OPH}, I_{OPL} - Ta$



RESTRICTIONS ON PRODUCT USE

000707EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.